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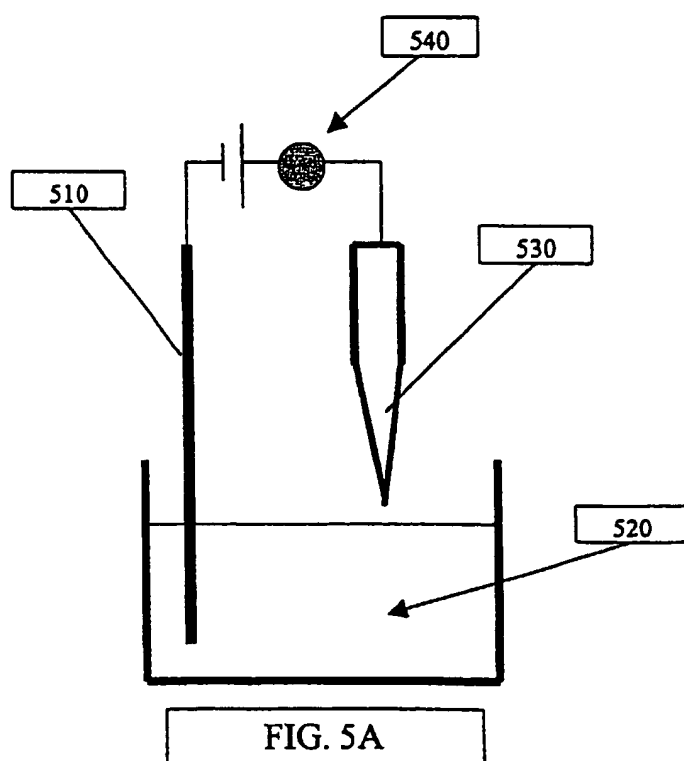
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(54) Title: DEPOSITION METHOD FOR NANOSTRUCTURE MATERIALS



(57) Abstract: A method for depositing a coating of a nanostucture material onto a substrate includes : 1) forming a solution or suspension (520) of containing the nanostucture material; 2) selectively adding "charger" to the solution (520); 3) immersing electrodes (510, 530) in the solution (520), the substrate upon which the nanostucture material is to be deposited acting as one of the electrodes; 4) applying a direct and/or alternating current electrical field between the two electrodes (510, 530) for a certain period of time thereby causing the nanostucture materials in the solution (520) to migrate toward and attach themselves to the substrate electrode (530); and 5) subsequently optional processing of the coated substrate.

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Declarations under Rule 4.17:

- as to applicant's entitlement to apply for and be granted a patent (Rule 4.17(ii)) for the following designations AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BY, BZ, CA, CH, CN, CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, ES, FI, GB, GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, MA, MD, MG, MK, MN, MW, MX, MZ, NO, NZ, OM, PH, PL, PT, RO, RU, SD, SE, SG, SI, SK, SL, TJ, TM, TN, TR, TT, TZ, UA, UG, UZ, VC, VN, YU, ZA, ZM, ZW, ARIPO patent (GH, GM, KE, LS, MW, MZ, SD, SL, SZ, TZ, UG, ZM, ZW), Eurasian patent (AM, AZ, BY, KG, KZ, MD, RU, TJ, TM), European patent (AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, IE, IT, LU, MC, NL, PT, SE, SK, TR), OAPI patent (BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG)
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MN, MW, MX, MZ, NO, NZ, OM, PH, PL, PT, RO, RU, SD, SE, SG, SI, SK, SL, TJ, TM, TN, TR, TT, TZ, UA, UG, UZ, VC, VN, YU, ZA, ZM, ZW, ARIPO patent (GH, GM, KE, LS, MW, MZ, SD, SL, SZ, TZ, UG, ZM, ZW), Eurasian patent (AM, AZ, BY, KG, KZ, MD, RU, TJ, TM), European patent (AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, IE, IT, LU, MC, NL, PT, SE, SK, TR), OAPI patent (BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG)

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B. FIELDS SEARCHED

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Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched

Electronic data base consulted during the international search (name of data base and, where practicable, search terms used)
WEST

C. DOCUMENTS CONSIDERED TO BE RELEVANT

Category *	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
X — Y	AFFOUNE et al. "Electrophoretic Deposition of Nanosized Diamond Particles", Langmuir 2001, 17, pp. 547-551.	1-8, 12, 13, 16, 18 and 22-24 9-11, 14, 15, 17, 19-21, 25-73
X — Y	US 6,258,237 A (GAL-OR et al.) 10 July 2001, see Examples and col. 10, lines 61-62.	1-8, 12, 13, 16, 22, 24, 28 and 29 15, 19-21 and 25-27
Y	US 5,296,117 A (DE JAEGER et al.) 22 March 1994, paragraph crossing cols. 10 and 11.	25-27

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☐ See patent family annex.

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"P" document published prior to the international filing date but later than the priority date claimed	

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